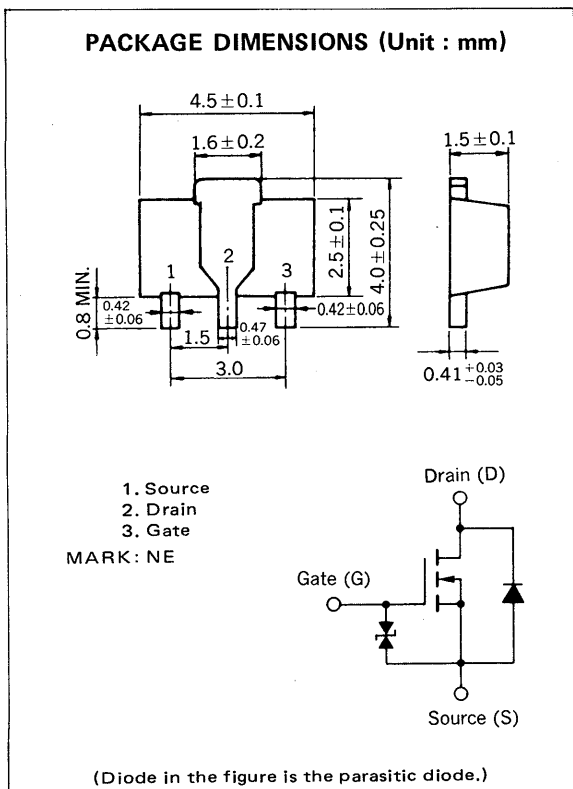


N-CHANNEL MOS FET
FOR SWITCHING



The 2SK1585 is an N-channel vertical type MOS FET which can be driven by 2.5 V power supply.

As the MOS FET is driven by low voltage and does not require consideration of driving current, it is suitable for appliances including VCR cameras and headphone stereos which need power saving.

FEATURES

- Directly driven by ICs having a 3 V power supply.
- Has low on-state resistance.
 $R_{DS(on)1} = 1.2 \Omega \text{ MAX. @ } V_{GS} = 2.5 \text{ V, } I_D = 0.5 \text{ A}$
 $R_{DS(on)2} = 1.0 \Omega \text{ MAX. @ } V_{GS} = 4.0 \text{ V, } I_D = 0.5 \text{ A}$

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

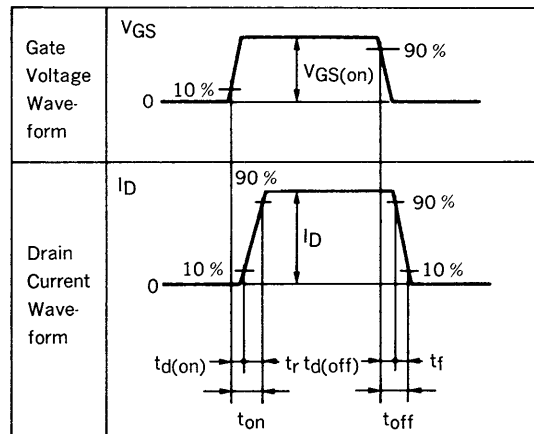
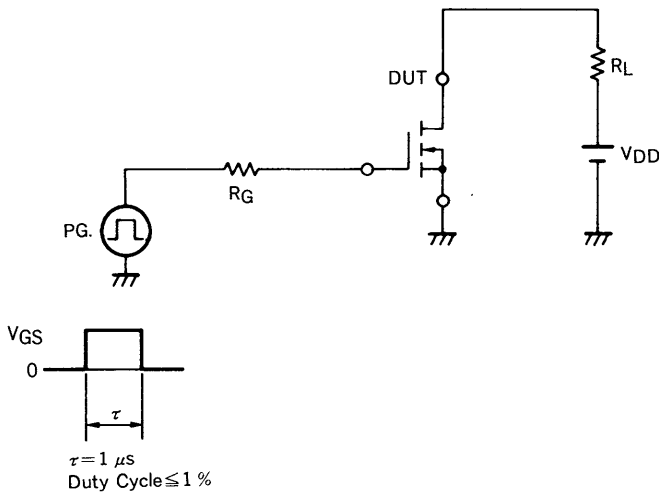
ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V_{DSS}	16	V	$V_{GS} = 0$
Gate to Source Voltage	V_{GSS}	±16	V	$V_{DS} = 0$
Drain Current	$I_D(\text{DC})$	±1.0	A	
Drain Current	$I_D(\text{pulse})$	±2.0	A	$PW \leq 10 \text{ ms, Duty Cycle} \leq 50 \%$
Total Power Dissipation	P_T	2.0	W	When using ceramic board of $16 \text{ cm}^2 \times 0.7 \text{ mm}$
Channel Temperature	T_{ch}	150	°C	
Operating Temperature	T_{opt}	-55 to +80	°C	
Storage Temperature	T_{stg}	-55 to +150	°C	

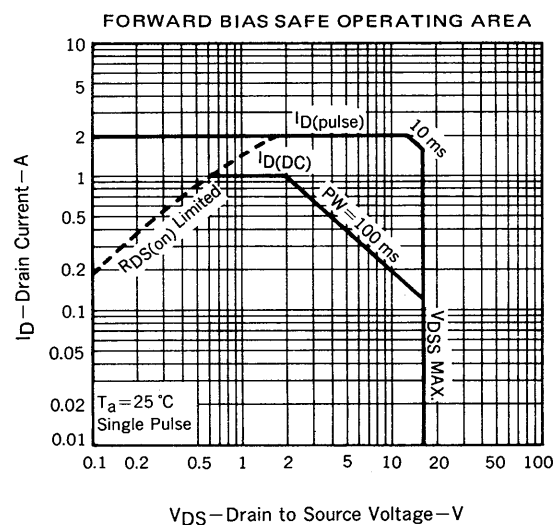
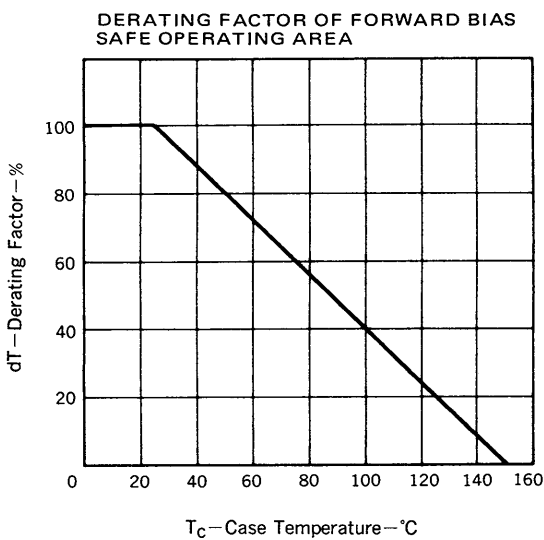
ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

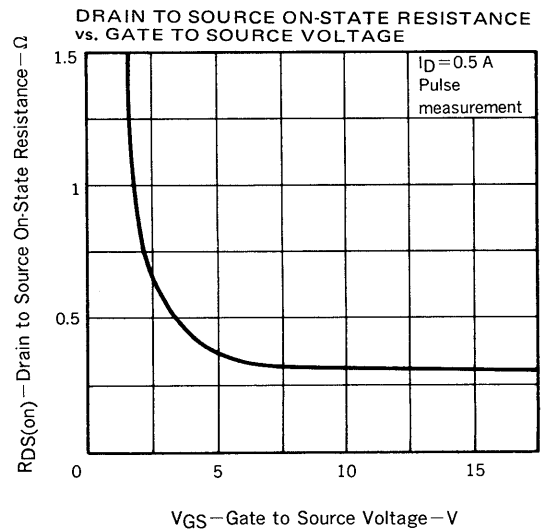
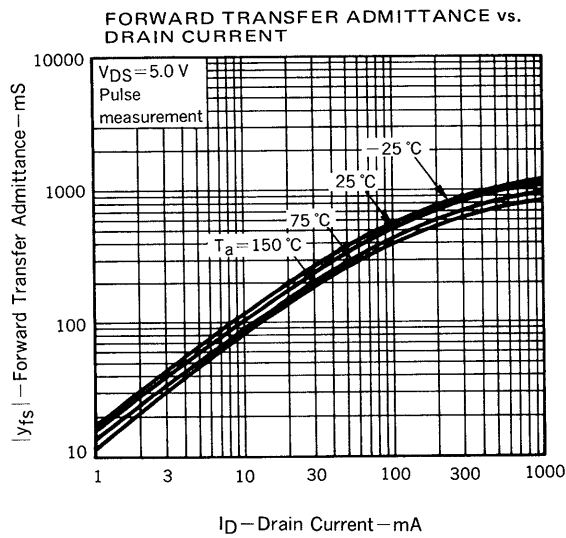
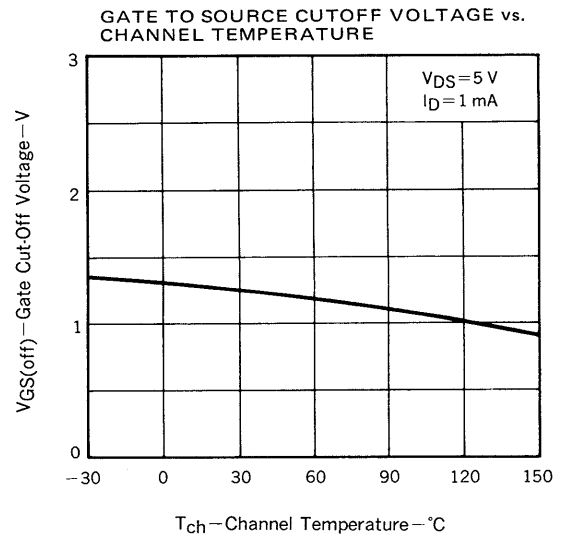
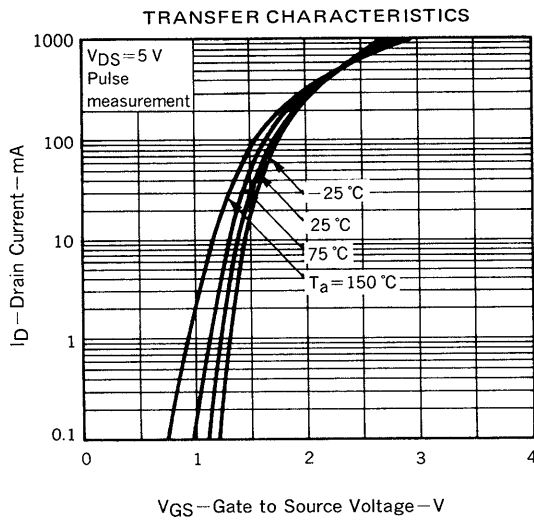
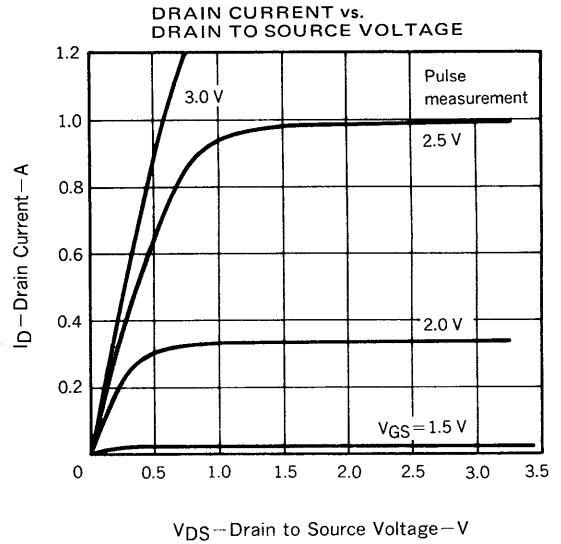
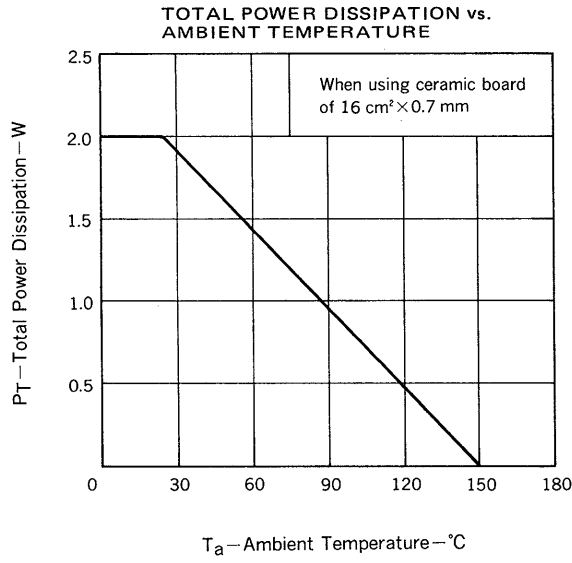
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	I_{DSS}			1.0	μA	$V_{DS} = 16\text{ V}, V_{GS} = 0$
Gate Leakage Current	I_{GSS}			± 5.0	μA	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0$
Gate Cut-off Voltage	$V_{GS(off)}$	0.8	1.2	1.6	V	$V_{DS} = 5\text{ V}, I_D = 1\text{ mA}$
Forward Transfer Admittance	$ y_{fs} $	0.4	1.0		S	$V_{DS} = 5\text{ V}, I_D = 0.5\text{ A}$
Drain to Source On-State Resistance	$R_{DS(on)1}$		0.6	1.2	Ω	$V_{GS} = 2.5\text{ V}, I_D = 0.5\text{ A}$
Drain to Source On-State Resistance	$R_{DS(on)2}$		0.3	1.0	Ω	$V_{GS} = 4.0\text{ V}, I_D = 0.5\text{ A}$
Input Capacitance	C_{iss}		116		pF	$V_{DS} = 3\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$
Output Capacitance	C_{oss}		107		pF	
Feedback Capacitance	C_{rss}		27		pF	
Turn-On Delay Time	$t_{d(on)}$		80		ns	$V_{GS(on)} = 3\text{ V}, R_G = 10\ \Omega$ $V_{DD} = 3.0\text{ V}, I_D = 0.5\text{ A}$ $R_L = 6\ \Omega$
Rise Time	t_r		260		ns	
Turn-Off Delay Time	$t_{d(off)}$		145		ns	
Fall Time	t_f		140		ns	

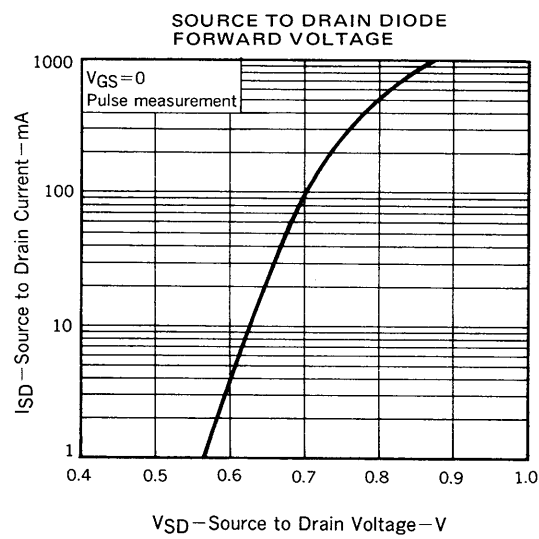
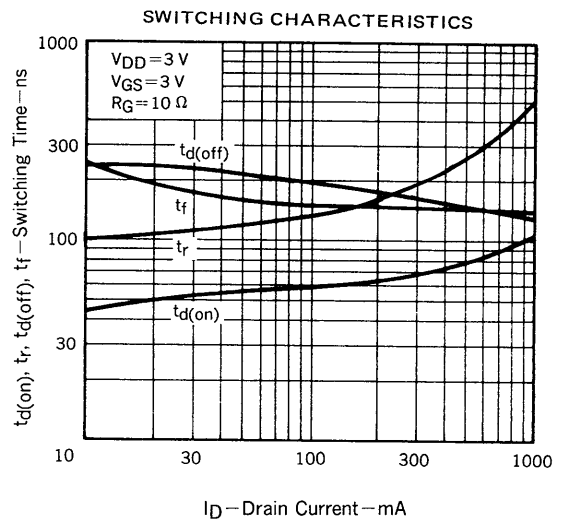
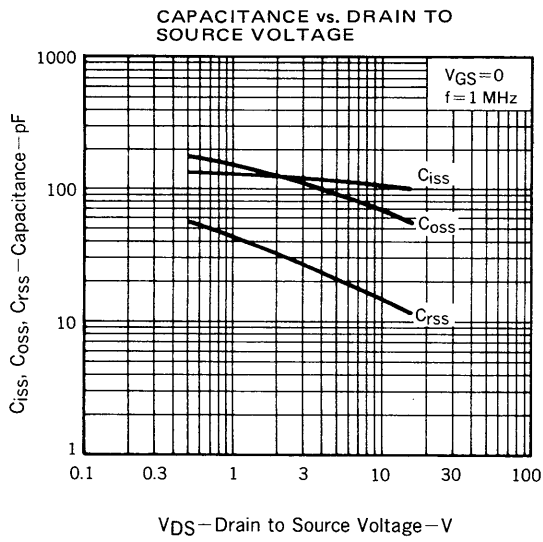
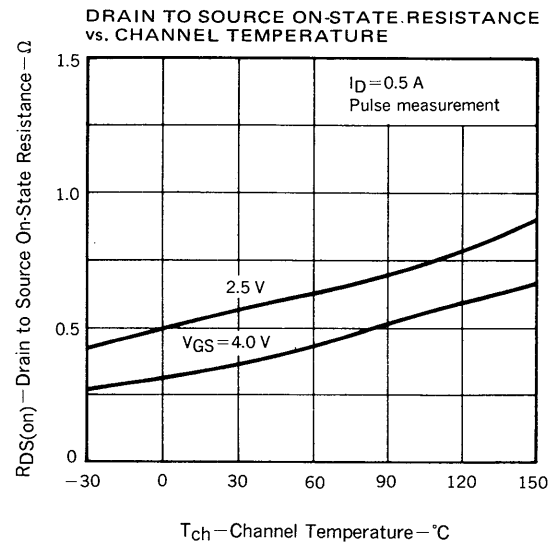
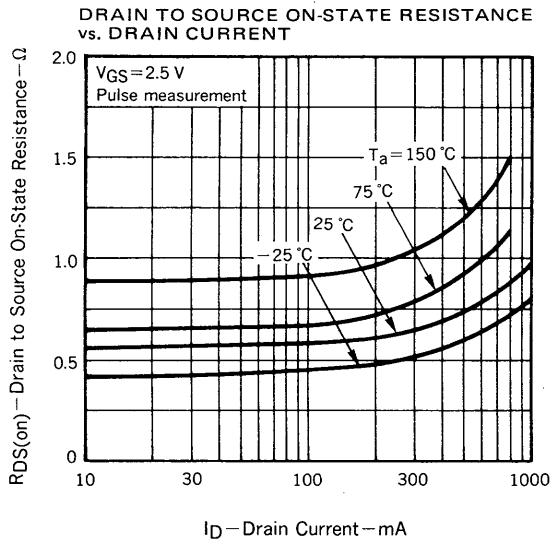
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)







RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.
Please consult our representatives about soldering methods and conditions other than these.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document "SMT MANUAL" (IEI-1207).

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00

*: Stored days under storage conditions at 25 °C and below 65 % R.H. after the dry-pack has been opened.

Note 1 Combination of soldering methods should be avoided.

REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134

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Application examples recommended by NEC Corporation

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.